

## 500 mW DO-35 Hermetically Sealed Glass Zener Voltage Regulators



### Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Parameter	Value	Units
Power Dissipation	500	mW
Storage Temperature Range	-65 to +175	°C
Operating Junction Temperature	+175	°C

DEVICE MARKING DIAGRAM

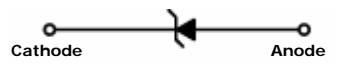


Voltage Code : XXX

These ratings are limiting values above which the serviceability of the diode may be impaired.

### Specification Features:

- Zener Voltage Range 2.0 to 36 Volts
- DO-35 Package (JEDEC)
- Through-Hole Device Type Mounting
- Hermetically Sealed Glass
- Compression Bonded Construction
- All External Surfaces Are Corrosion Resistant And Leads Are Readily Solderable
- RoHS Compliant and Halogen Free
- Solder Hot Dip Tin (Sn) Terminal Finish
- Cathode Indicated By Polarity Band



ELECTRICAL SYMBOL

### Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Type	Grade	Zener Voltage		Reverse Current		Dynamic Resistance	
		VZ(Volts)		Test Condition	IR ( $\mu\text{A}$ )	Test Condition	$Z_{ZT} @ I_{ZT} (\Omega)$
		Min	Max				
HZ2	B1	1.9	2.1	5	5	0.5	100
	B2	2.0	2.2				
	B3	2.1	2.3				
	C1	2.2	2.4				
	C2	2.3	2.5				
	C3	2.4	2.6				
HZ3	A1	2.5	2.7	5	5	0.5	100
	A2	2.6	2.8				
	A3	2.7	2.9				
	B1	2.8	3.0				
	B2	2.9	3.1				
	B3	3.0	3.2				
	C1	3.1	3.3				
	C2	3.2	3.4				
	C3	3.3	3.5				



SEMICONDUCTOR

Electrical Characteristics ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Type	Grade	Zener Voltage		Reverse Current		Dynamic Resistance	
		VZ(Volts)		Test Condition Iz (mA)	IR ( $\mu\text{A}$ ) Max	Test Condition VR (V)	Z <sub>ZT</sub> @ I <sub>ZT</sub> ( $\Omega$ )
		Min	Max				Iz (mA)
HZ4	A1	3.4	3.6	5	5	1	100
	A2	3.5	3.7				
	A3	3.6	3.8				
	B1	3.7	3.9				
	B2	3.8	4.0				
	B3	3.9	4.1				
	C1	4.0	4.2				
	C2	4.1	4.3				
	C3	4.2	4.4				
HZ5	A1	4.3	4.5	5	5	1.5	100
	A2	4.4	4.6				
	A3	4.5	4.7				
	B1	4.6	4.8				
	B2	4.7	4.9				
	B3	4.8	5.0				
	C1	4.9	5.1				
	C2	5	5.2				
	C3	5.1	5.3				
HZ6	A1	5.2	5.5	5	5	2	40
	A2	5.3	5.6				
	A3	5.4	5.7				
	B1	5.5	5.8				
	B2	5.6	5.9				
	B3	5.7	6				
	C1	5.8	6.1				
	C2	6	6.3				
	C3	6.1	6.4				
HZ7	A1	6.3	6.6	5	1	3.5	15
	A2	6.4	6.7				
	A3	6.6	6.9				
	B1	6.7	7				
	B2	6.9	7.2				
	B3	7	7.3				
	C1	7.2	7.6				
	C2	7.3	7.7				
	C3	7.5	7.9				
HZ9	A1	7.7	8.1	5	1	5	20
	A2	7.9	8.3				
	A3	8.1	8.5				
	B1	8.3	8.7				
	B2	8.5	8.9				
	B3	8.7	9.1				
	C1	8.9	9.3				
	C2	9.1	9.5				
	C3	9.3	9.7				



SEMICONDUCTOR

Electrical Characteristics ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Type	Grade	Zener Voltage		Reverse Current		Dynamic Resistance	
		VZ(Volts)		Test Condition Iz (mA)	IR ( $\mu\text{A}$ ) Max	Test Condition VR (V)	Z <sub>ZT</sub> @ I <sub>ZT</sub> ( $\Omega$ ) Max
		Min	Max				
HZ11	A1	9.5	9.9	5	1	7.5	25
	A2	9.7	10.1				
	A3	9.9	10.3				
	B1	10.2	10.6				
	B2	10.4	10.8				
	B3	10.7	11.1				
	C1	10.9	11.3				
	C2	11.1	11.6				
	C3	11.4	11.9				
HZ12	A1	11.6	12.1	5	1	9.5	35
	A2	11.9	12.4				
	A3	12.2	12.7				
	B1	12.4	12.9				
	B2	12.6	13.1				
	B3	12.9	13.4				
	C1	13.2	13.7				
	C2	13.5	14				
	C3	13.8	14.3				
HZ15	-1	14.1	14.7	5	1	11	40
	-2	14.5	15.1				
	-3	14.9	15.5				
HZ16	-1	15.3	15.9	5	1	12	45
	-2	15.7	16.5				
	-3	16.3	17.1				
HZ18	-1	16.9	17.7	5	1	13	55
	-2	17.5	18.3				
	-3	18.1	19				
HZ20	-1	18.8	19.7	2	1	15	60
	-2	19.5	20.4				
	-3	20.2	21.1				
HZ22	-1	20.9	21.9	2	1	17	65
	-2	21.6	22.6				
	-3	22.3	23.3				
HZ24	-1	22.9	24	2	1	19	70
	-2	23.6	24.7				
	-3	24.3	25.5				
HZ27	-1	25.2	26.6	2	1	21	80
	-2	26.2	27.6				
	-3	27.2	28.6				
HZ30	-1	28.2	29.6	2	1	23	100
	-2	29.2	30.6				
	-3	30.2	31.6				
HZ33	-1	31.2	32.6	2	1	25	120
	-2	32.2	33.6				
	-3	33.2	34.6				



SEMICONDUCTOR

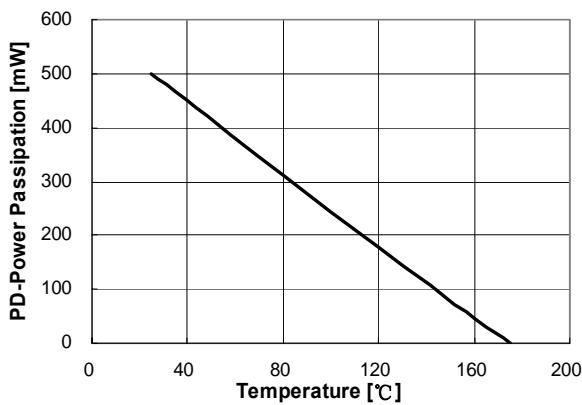
**Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Type	Grade	Zener Voltage		Reverse Current		Dynamic Resistance	
		VZ(Volts)		Test Condition Iz (mA)	IR ( $\mu\text{A}$ )	Test Condition VR (V)	Z <sub>ZT</sub> @ I <sub>ZT</sub> ( $\Omega$ )
		Min	Max				Iz (mA)
HZ36	-1	34.2	35.7	2	1	27	140
	-2	35.3	36.8				
	-3	36.4	38				

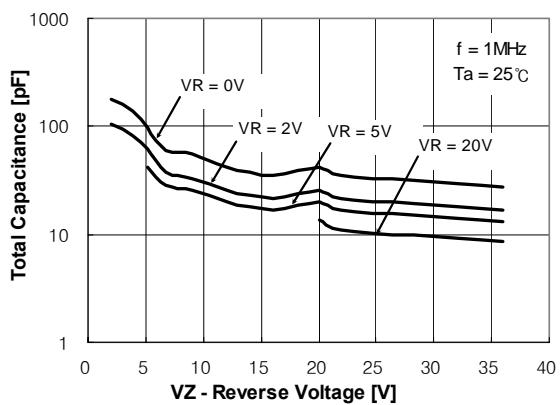
**V<sub>F</sub>** Forward Voltage = 1.2 V Maximum @ I<sub>F</sub> = 200 mA for all types**Notes:**

1. The zener voltage (V<sub>Z</sub>) is tested under pulse condition.
2. The dynamic resistance Z<sub>ZT</sub> is measured by dividing the AC voltage drop across the device by the AC current applied. The specified limits are for I<sub>Z(AC)</sub> = 0.1 I<sub>Z(DC)</sub> with AC frequency = 60Hz.
3. Type No. is as follows; TC2B1, TC2B2, TC36-3.

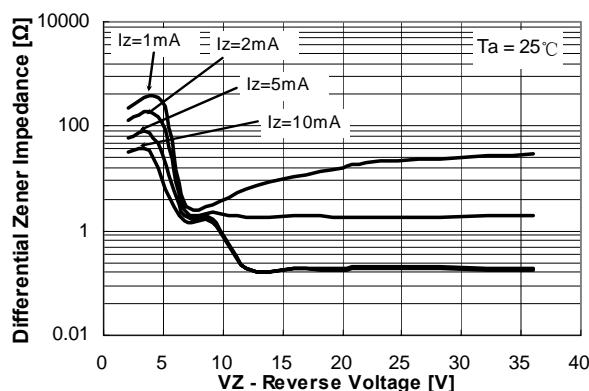
## Typical Characteristics



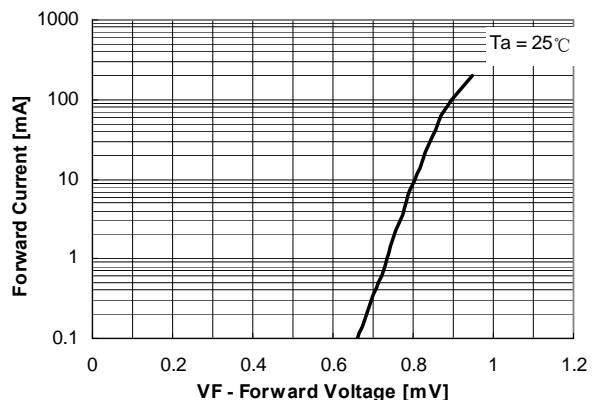
**Figure 1. Power Dissipation vs Ambient Temperature**  
Valid provided leads at a distance of 0.8mm from case are kept at ambient temperature



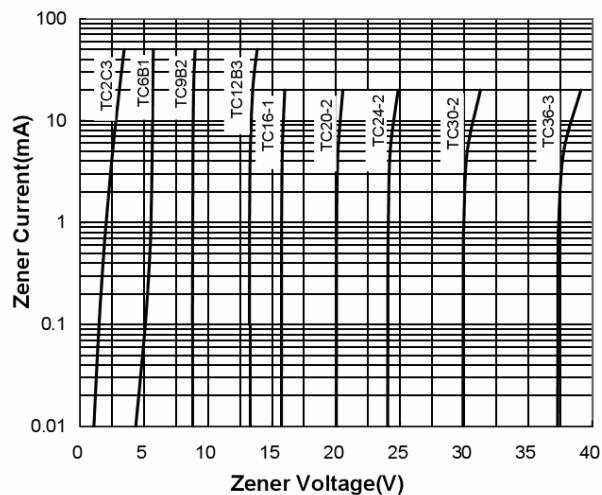
**Figure 2. Total Capacitance**



**Figure 3. Differential Impedance vs. Zener Voltage**



**Figure 4. Forward Current vs. Forward Voltage**



**Figure 5. Zener Current vs. Zener Voltage**

**Package Outline**

Package	Case Outline				
DO-35					
	DO-35				
	DIM	Millimeters		Inches	
		Min	Max	Min	Max
	A	0.46	0.55	0.018	0.022
	B	3.05	5.08	0.120	0.200
C	25.40	38.10	1.000	1.500	
D	1.53	2.28	0.060	0.090	

**Notes:**

1. All dimensions are within JEDEC standard.
2. DO35 polarity denoted by cathode band.